





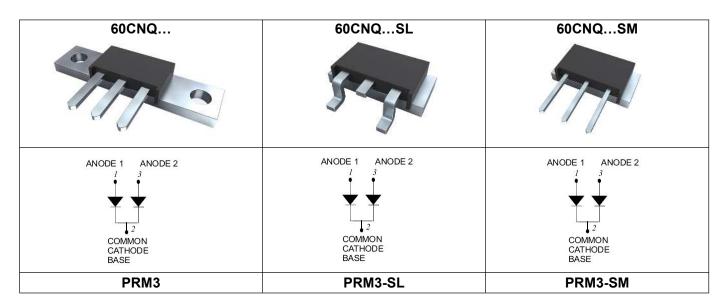
# **60CNQ SERIES SCHOTTKY RECTIFIER**

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Features**

- 150°C T<sub>J</sub> operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	35(60CNQ035) 40(60CNQ040) 45(60CNQ045)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =116°C, rectangular wave form	30(Per Leg) 60(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1020	А
Non-Repetitive Avalanche Energy (Peg leg)	Eas	T <sub>J</sub> =25℃,I <sub>AS</sub> =6A,L=2.2mH	40	mJ
Repetitive Avalanche Current(Peg leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by $T_J$ max. $V_A$ =1.5× $V_R$ typical	6	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25 °C @ 60A, Pulse, T <sub>J</sub> = 25 °C	0.49 0.58	0.55 0.64	V
	V <sub>F2</sub>	@ 30A, Pulse, T <sub>J</sub> = 125 °C @ 60A, Pulse, T <sub>J</sub> = 125 °C	0.40 0.51	0.44 0.59	V
Reverse Current (Per leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.1	5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	80	200	mA
Junction Capacitance (Per leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	2000	2600	pF
Series Inductance (Per leg)	Ls	Measured lead to lead 5 mm from package body	6.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

### **Thermal-Mechanical Specifications:**

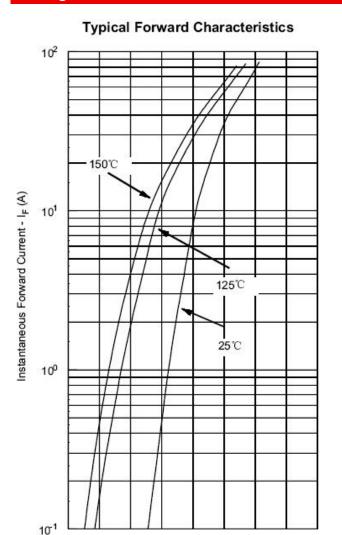
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	ΤJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	Rejc	DC operation	0.85	°C/W
Typical Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.42	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.30	°C/W
Mounting Torque	TM	-	40(min) 58(max)	Kg-cm
Approximate Weight	wt	-	7.8	g
Case Style	PRM3 PRM3-SL PRM3-SM			



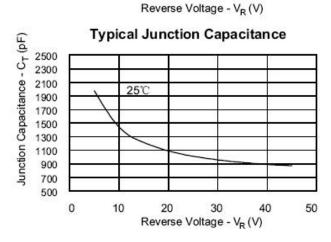




### **Ratings and Characteristics Curves**



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20

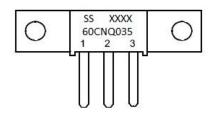
30

40

50

### **Marking Diagram**

0.0

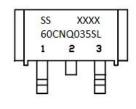


0.2

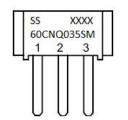
0.4

Forward Voltage Drop - VF (V)

0.6



0.8



0

10

Where XXXX is YYWW

1st row SS YYWWL 2nd row 60CNQ035/SL/SM 3rd row 1 2 3 (pin) SS = SS

SS = SS YY = Year WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

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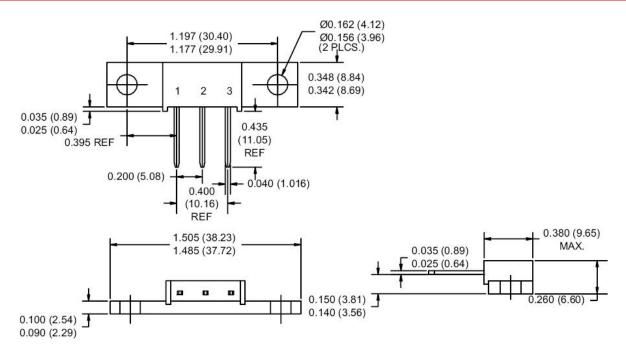




### **Ordering Information**

Device	Package	Terminals finish	Baseplate finish	Shipping
60CNQ035	PRM3	Nickel plated	Nickel plated	48pcs / box
60CNQ035S2	PRM3	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
60CNQ040	PRM3	Nickel plated	Nickel plated	48pcs / box
60CNQ040S2	PRM3	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
60CNQ045	PRM3	Nickel plated	Nickel plated	48pcs / box
60CNQ045S2	PRM3	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
60CNQ035SL	PRM3-SL	Pure Sn plated	Pure Sn plated	100pcs / box
60CNQ040SL	PRM3-SL	Pure Sn plated	Pure Sn plated	100pcs / box
60CNQ045SL	PRM3-SL	Pure Sn plated	Pure Sn plated	100pcs / box
60CNQ035SM	PRM3-SM	Nickel plated	Nickel plated	48pcs / box
60CNQ035SMS2	PRM3-SM	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
60CNQ040SM	PRM3-SM	Nickel plated	Nickel plated	48pcs / box
60CNQ040SMS2	PRM3-SM	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
60CNQ045SM	PRM3-SM	Nickel plated	Nickel plated	48pcs / box
60CNQ045SMS2	PRM3-SM	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

### **Mechanical Dimensions PRM3 (Inches/Millimeters)**



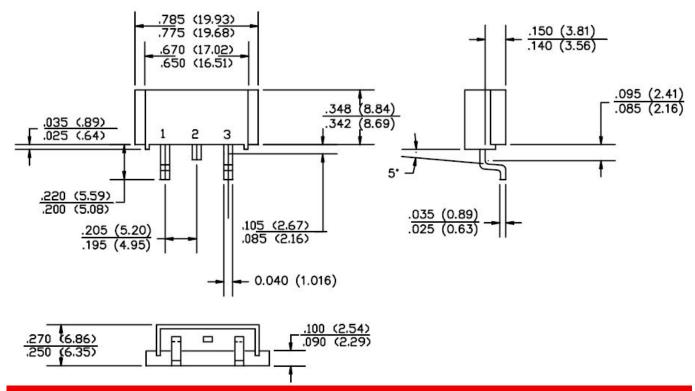
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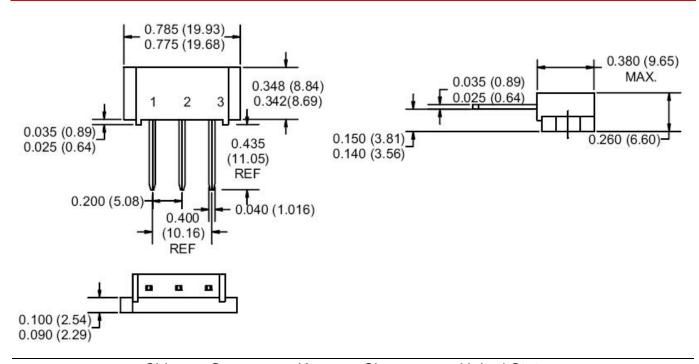




### Mechanical Dimensions PRM3-SL (Inches/Millimeters)



### **Mechanical Dimensions PRM3-SM (Inches/Millimeters)**



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